NSN 5961-01-100-5886

Thyristor Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-100-5886 **Inclosure Material:** Metal **Overall Length:** 1.222 inches **End Application:** T-38, b-52 stratofortress aircraft. **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.427 inches and 0.437 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 2.00 amperes zero-gate-voltage source current torr **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector not applicable **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Weapon system essential **Test Data Document:** 13499-353-6508 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-100-5886

Thyristor Semiconductor Device - Page 2 of 2



Fiig:

A110a0